

NPN PRE-BIASED SMALL SIGNAL DUAL SURFACE MOUNT TRANSISTOR
Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDA)
- Built-In Biasing Resistors
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Part Number	R1 (NOM)	R2 (NOM)
DDC124EU	22KΩ	22KΩ
DDC144EU	47KΩ	47KΩ
DDC114YU	10KΩ	47KΩ
DDC123JU	2.2KΩ	47KΩ
DDC114EU	10KΩ	10KΩ

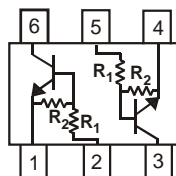
Mechanical Data

- Case: SOT363
- Case material: Molded Plastic. "Green" Molding Compound.
- Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.006 grams (approximate)

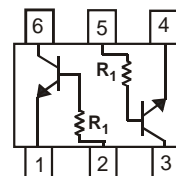
Part Number	R1 Only
DDC113TU	1KΩ
DDC143TU	4.7KΩ
DDC114TU	10KΩ



Top View



R1, R2



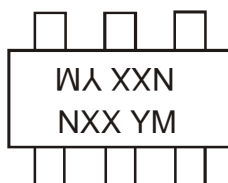
R1 Only

Device Schematic

Ordering Information (Note 3 & 4)

Product	Grade	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DDC124EU-7-F	Commercial	N17	7	8	3,000
DDC124EUQ-7-F	Automotive	N17	7	8	3,000
DDC124EUQ-13-F	Automotive	N17	13	8	10,000
DDC144EU-7-F	Commercial	N20	7	8	3,000
DDC114YU-7-F	Commercial	N14	7	8	3,000
DDC114YUQ-7-F	Automotive	N14	7	8	3,000
DDC123JU-7-F	Commercial	N06	7	8	3,000
DDC114EU-7-F	Commercial	N13	7	8	3,000
DDC114EUQ-7-F	Automotive	N13	7	8	3,000
DDC114EUQ-13-F	Automotive	N13	13	8	10,000
DDC113TU-7-F	Commercial	N01	7	8	3,000
DDC143TU-7-F	Commercial	N07	7	8	3,000
DDC114TU-7-F	Commercial	N12	7	8	3,000
DDC114TUQ-7-F	Automotive	N12	7	8	3,000

- Notes:
1. No purposefully added lead.
 2. Diodes Inc's "Green" policy can be found on our website at <http://www.diodes.com>.
 3. For packaging details, go to our website at <http://www.diodes.com>.
 4. Products with Q-suffix are automotive grade. Automotive products are electrical and thermal the same as the commercial, except where specified.

Marking Information


NXX = Product Type Marking Code
 See Page 1 Diagrams
 YM = Date Code Marking
 Y = Year (ex: T = 2006)
 M = Month (ex: 9 = September)

Date Code Key

Year	2010	2011	2012	2013	2014	2015	2016	2017				
Code	X	Y	Z	A	B	C	D	E				
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Supply Voltage		V _{CC}	50	V
Input Voltage	DDC124EU	V _{IN}	-10 to +40	V
	DDC144EU		-10 to +40	
	DDC114YU		-6 to +40	
	DDC123JU		-5 to +12	
	DDC114EU		-10 to +40	
	DDC113TU		-5V max	
	DDC143TU		-5V max	
DDC114TU	-5V max			
Output Current		I _{C(MAX)}	100	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	150	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	833	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 5. Mounted on FR4 PC Board with minimum recommended pad layout

Electrical Characteristics @T_A = 25°C unless otherwise specified

For R1 only devices: DDC113TU & DDC143TU & DDC114TU

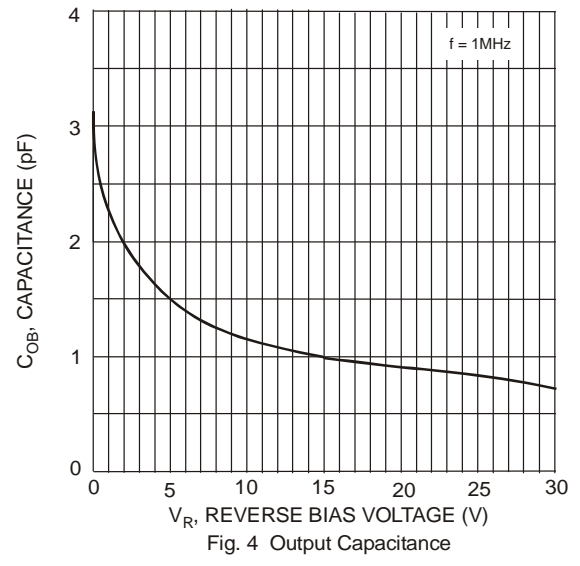
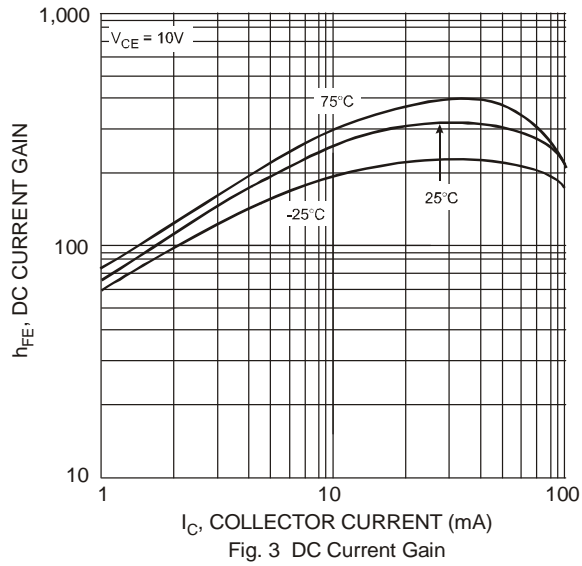
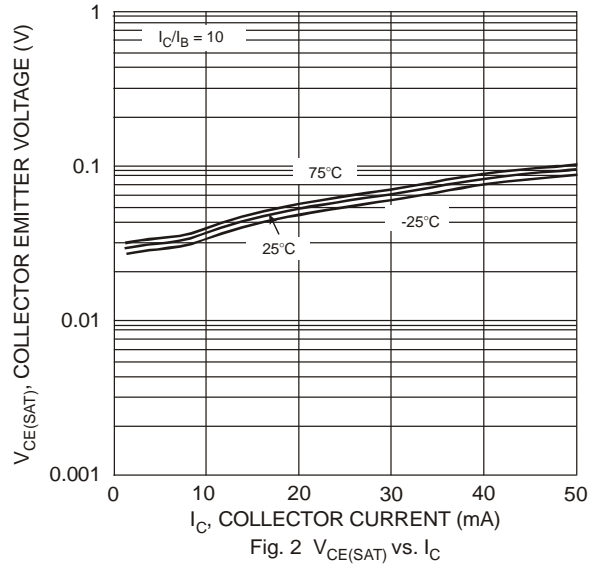
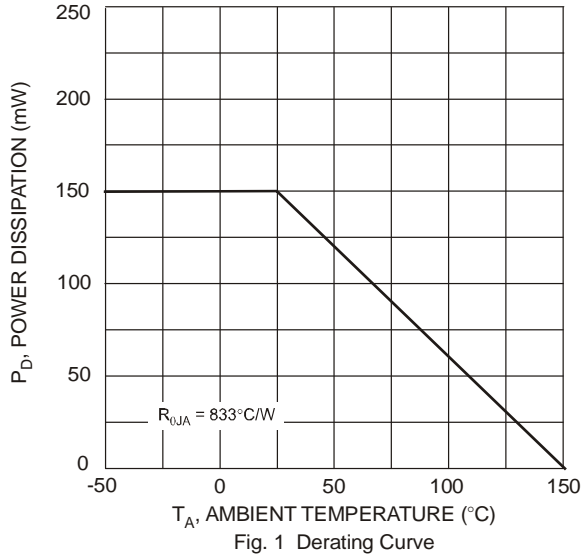
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	—	—	V	I _C = 50μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	50	—	—	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	5	—	—	V	I _E = 50μA
Collector Cutoff Current	I _{CBO}	—	—	0.5	μA	V _{CB} = 50V
Emitter Cutoff Current	I _{EBO}	—	—	0.5	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	—	0.3	V	I _C /I _B = 2.5mA / 0.25mA DDC143TU I _C /I _B = 1mA / 0.1mA DDC114TU I _C /I _B = 10mA / 1mA DDC113TU
DC Current Transfer Ratio	h _{FE}	100	250	600	—	I _C = 1mA, V _{CE} = 5V
Input Resistor (R ₁) Tolerance	ΔR ₁	-30	—	+30	%	—
Gain-Bandwidth Product (Note 6)	f _T	—	250	—	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz

For R1, R2 devices: DDC124EU & DDC144EU & DDC114YU & DDC123JU & DDC114EU

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	V _{I(off)}	0.5	1.1	—	V	V _{CC} = 5V, I _O = 100μA
		0.5	1.1	—		
Input Voltage	V _{I(on)}	0.3	—	—	V	V _O = 0.3, I _O = 5mA V _O = 0.3, I _O = 2mA V _O = 0.3, I _O = 1mA V _O = 0.3, I _O = 5mA V _O = 0.3, I _O = 10mA
		0.5	—	—		
		0.5	1.9	3.0		
		—	1.9	3.0		
		—	1.4	1.1		
Output Voltage	V _{O(on)}	—	0.1	0.3	V	I _O /I _I = 10mA / 0.5mA I _O /I _I = 10mA / 0.5mA I _O /I _I = 5mA / 0.25mA I _O /I _I = 5mA / 0.25mA I _O /I _I = 10mA / 0.5mA
		—	—	—		
		—	—	—		
		—	—	—		
		—	—	—		
Input Current	I _I	—	—	0.36	mA	V _I = 5V
		—	—	0.18		
		—	—	0.88		
		—	—	3.6		
		—	—	0.88		
Output Current	I _{O(off)}	—	—	0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	G _I	56	—	—	—	V _O = 5V, I _O = 5mA V _O = 5V, I _O = 5mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 5mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 5mA
		68	—	—		
		68	—	—		
		80	—	—		
		80	—	—		
		30	—	—		
Input Resistor (R ₁) Tolerance	ΔR ₁	-30	—	+30	%	—
Resistance Ratio Tolerance	R ₂ /R ₁	-20	—	+20	%	—
Gain-Bandwidth Product (Note 6)	f _T	—	250	—	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

Notes: 6. Transistor - For Reference Only

Typical Curves – DDC123JU One Section



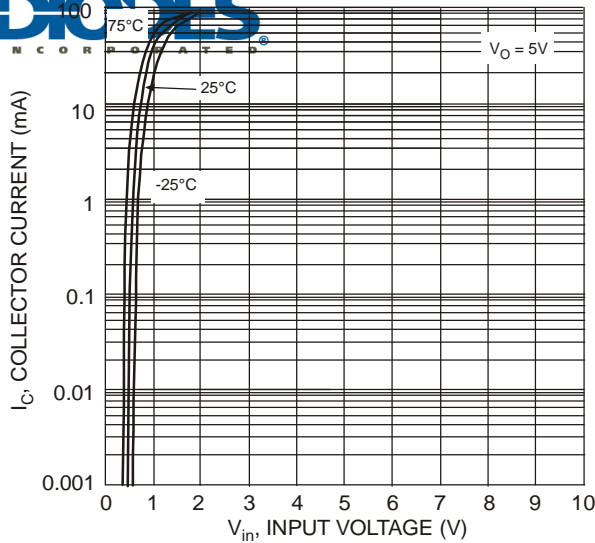


Fig. 5 Collector Current vs. Input Voltage

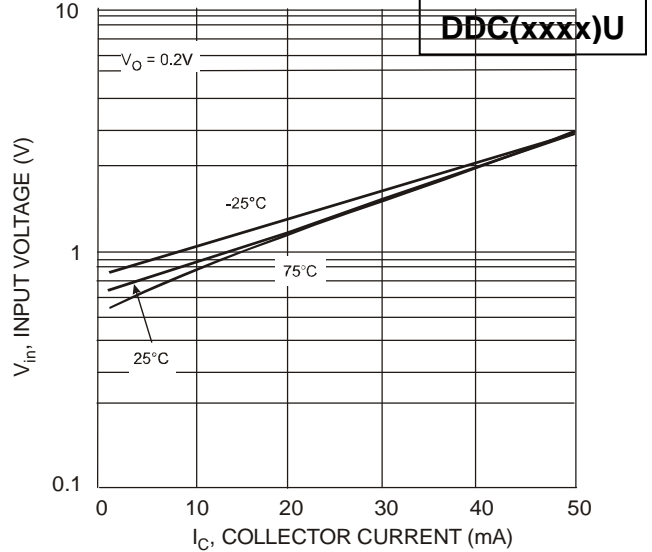


Fig. 6 Input Voltage vs. Collector Current

Typical Curves – DDC114YU One Section

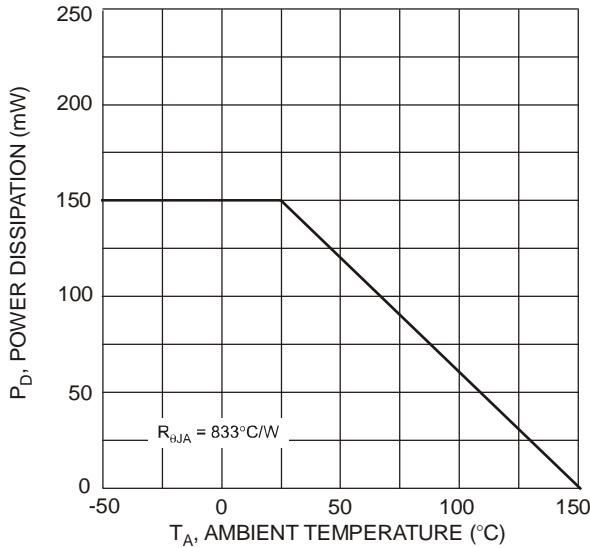


Fig. 1 Derating Curve

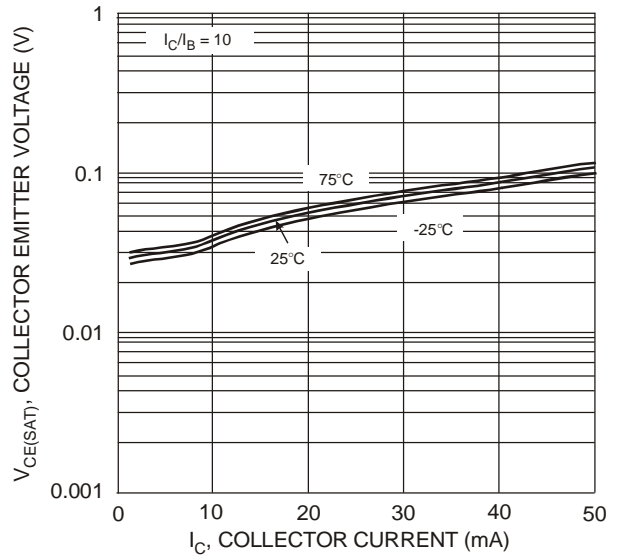


Fig. 2 $V_{CE(SAT)}$ vs. I_C

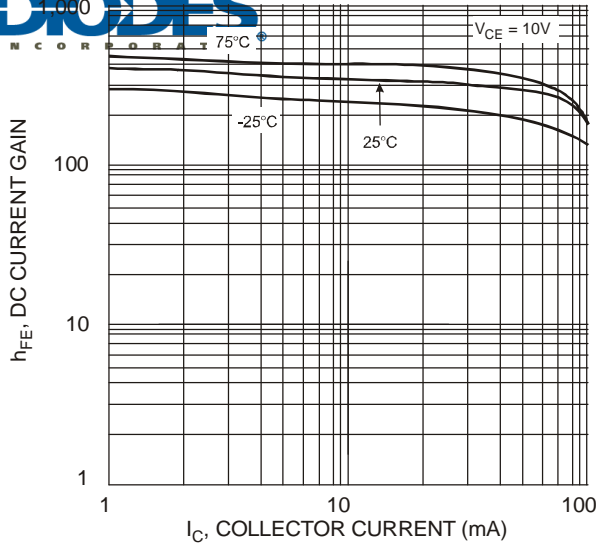


Fig. 3 DC Current Gain

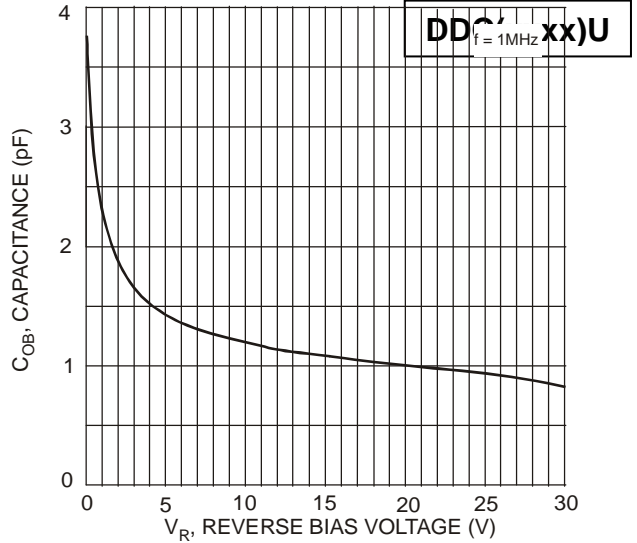


Fig. 4 Output Capacitance

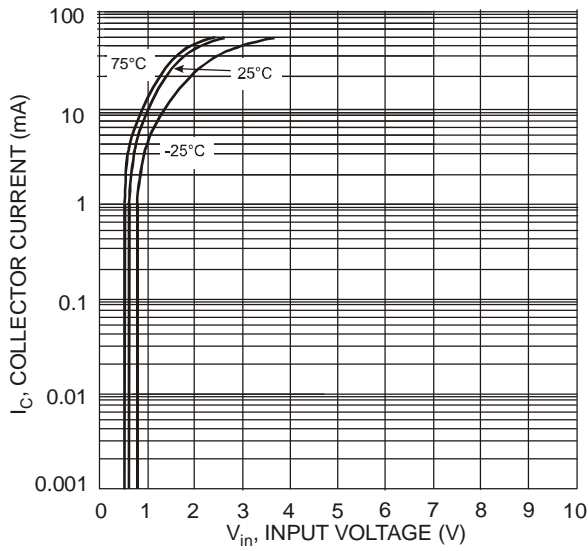


Fig. 5 Collector Current vs. Input Voltage

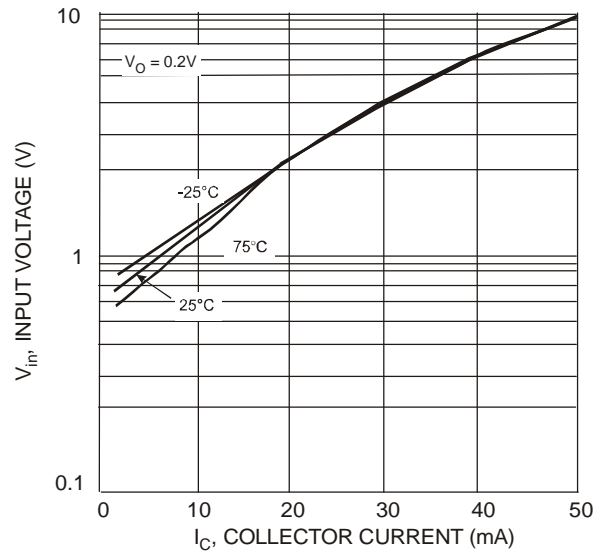


Fig. 6 Input Voltage vs. Collector Current

Typical Curves – DDC124EU One Section

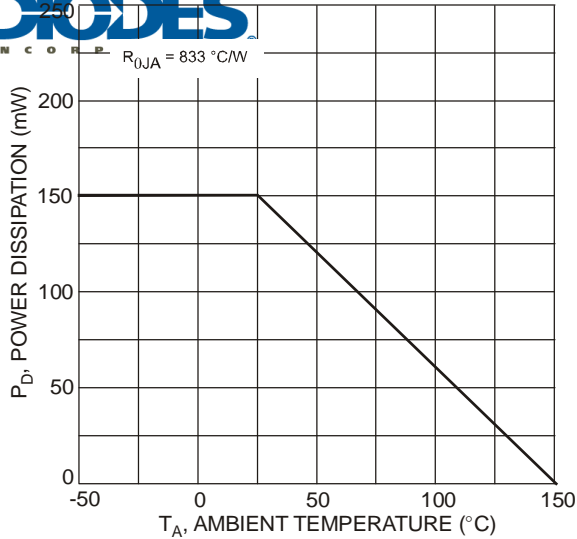


Fig. 1 Power Dissipation vs. Ambient Temperature

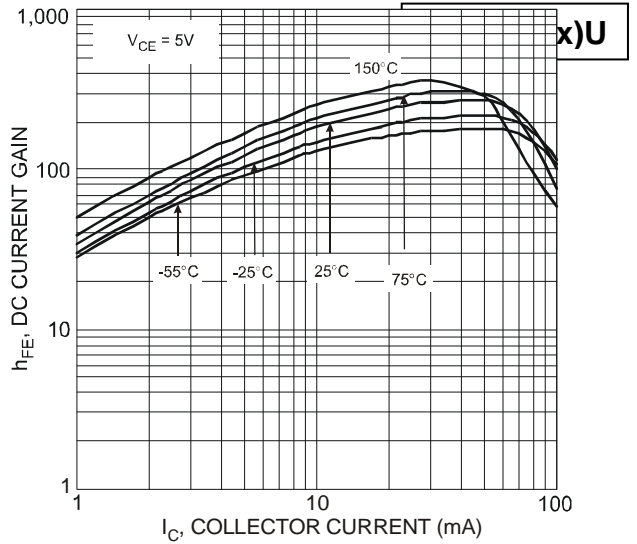


Fig. 2 Typical DC Current Gain vs. Collector Current

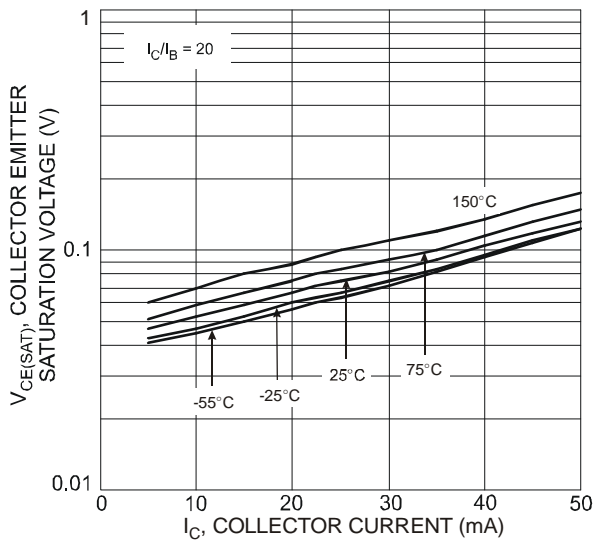


Fig. 3 Collector Emitter Saturation Voltage vs. Collector Current

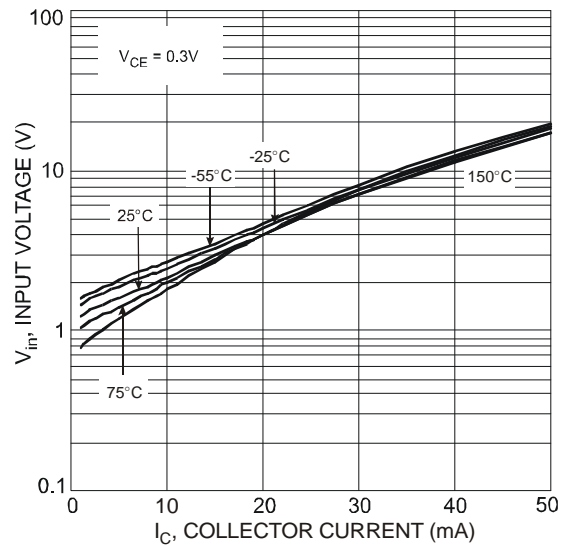
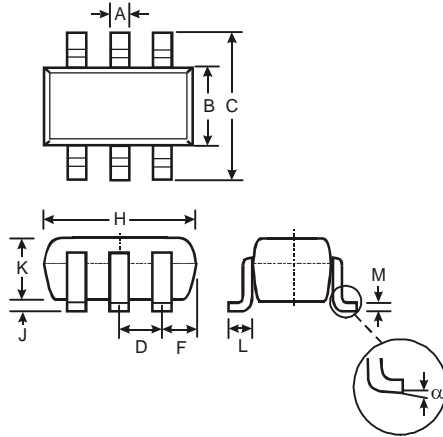


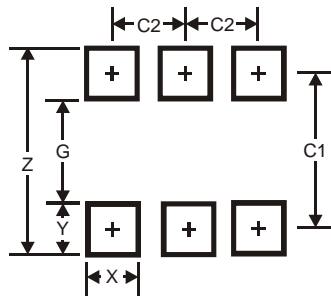
Fig. 4 Input Voltage vs. Collector Current

Package Outline Dimensions



SOT363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
H	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

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Офис по работе с юридическими лицами:

107023, г.Москва, Семеновский переулок, д.6, Бизнес-центр «АВС»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru_3	moschip.ru_6
moschip.ru_4	moschip.ru_7
moschip.ru_11	moschip.ru_8
moschip.ru_12	moschip.ru_9